

Introduction



In most circuit designs real-estate is a premium. This is especially true for the new generation of Home Gateway and Remote

Terminal voice circuits, where some solutions allocate less than one square inch for the SLIC and its components. With the development of Quad and Octal CODECS the SLIC now has a larger share of the solutions real-estate and a larger impact on area reduction. Small packaging has been around for some time, but there has not been a reliable, cost effective solution to significantly reduce the SLIC's area until now. The most significant hurdle has been the power dissipation capability of the package, which has been addressed with a new "Micro Lead Frame" Package technology. The improved thermal dissipation performance comes from the exposed lead frame that is used to help pull heat out of the die with the aid of thermal vias that tie directly to a heat sink plane. With this new technology Designers can take advantage of a 65% reduction in the RSLIC18's footprint (7mm x 7mm) and realize a significant improvement in thermal performance.

The Micro Lead Frame Plastic Package (MLFP) is a JEDEC standard package outline (EIA/JEDEC Publication 95, MO-220) and has several aliases. For example, depending on the manufacturer it may be referred to as a "Micro Lead Frame (MLF), a "Quad Flat No Lead Package" (QFN), or a "Lead Frame Chip Scale Package" (LFCSP).

Figure 1 illustrates a section view of a 16-Lead MLFP-package. The die pad and perimeter I/O pads are fabricated from a planar copper leadframe substrate. This is encapsulated in plastic with the bottom of the die attach and I/O pads exposed to create a very small footprint "exposed pad" package, ideal for today's dense high power Ringing SLIC solutions.

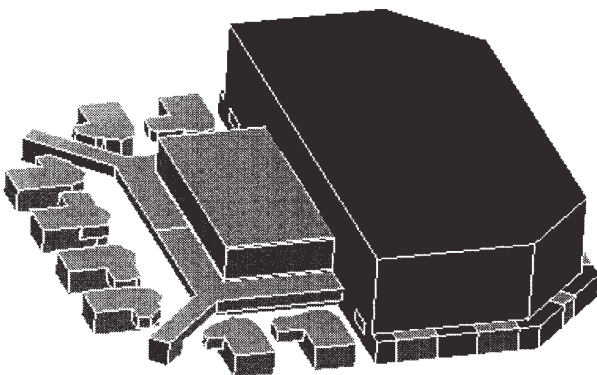


FIGURE 1. SECTION VIEW OF A 16-LEAD MICRO LEAD FRAME PACKAGE

The Concept of Thermal Resistance

The term "thermal resistance", denoted by the greek letter "theta" is frequently used to quantify the thermal performance of a packaged integrated circuit. For a semiconductor device the thermal resistance indicates the steady state temperature rise of the die junction above a given reference for each watt of power dissipated at the die surface (degrees centigrade/watt). A component manufacturer typically determines the junction to ambient thermal resistance (Theta-ja) by making physical measurements in a controlled laboratory environment and/or by computer simulation. The data includes the chips junction temperature (T_J), the ambient air temperature (T_A) in close proximity to the package, and the power dissipated by the IC (P_D). The theta-ja is calculated as follows;

$$\text{Theta-ja } (\theta_{JA}) = (T_J - T_A) / P_D, \text{ in Deg C/W} \quad (\text{EQ. 1})$$

Given the θ_{JA} and the power consumed by the die, a system level end user can estimate the die junction temperature from the equation below:

$$T_J = T_A + (\theta_{JA} * P_D) \quad (\text{EQ. 2})$$

Standardized Test Methods for Thermal Resistance Characterization

Theta-ja has historically been characterized in the laboratory with the device mounted on a variety of standardized printed circuit boards. Performing tests in a standardized way enables the circuit designer to easily compare the thermal performance of one package vs another for a given IC. If a component/package type combination performs better than another in a standardized test it will do so in the real application.

Many companies including Intersil follow the JEDEC EIA/JESD 51-X series standards, which define test methods, conditions and board design criteria. They are available at www.jedec.org under "Free Standards" area. Intersil's TB379 Tech Brief, Thermal Characterization of Packages for ICs provides additional information and references the applicable JEDEC specifications. It is available at www.intersil.com under the Design Support/Packaging Information section.

JEDEC focuses on two types of standard test boards for thermal resistance characterization. The first is the JESD51-3 low effective thermal conductivity test board with 2 ounce (0.070mm thick) surface copper I/O traces. It is commonly called "1S" or "1SOP" for one signal, 0 ground/power planes. The second board type is the JESD51-7 "high effective

thermal conductivity” board, and is more applicable for today’s multi layer PCBs. It adds two continuous, one ounce (0.035mm) buried copper planes, and is usually called 1S2P indicating 1 signal (top) and two buried planes. JEDEC has recently added the JESD51-5 “extension” standard for packages with direct thermal attachment mechanisms. This spec provides for surface attachment pads and copper plated thermal vias that connect directly to the upper buried plane of the 1S2P board. This new board type is called the 1S2P-DA where the “DA” stands for “direct attach”. It applies to exposed pad packages such as SOIC, TSSOP, TQFP, and the MLFP.

Power Estimates for Worst Case Conditions

It is important to understand the maximum power the SLIC is expected to dissipate in a given application to ensure safe and reliable operating conditions are met. As noted in the HC5518X data sheets the maximum recommended operating temperature is 150°C. The device also has a temperature sensing circuit on board that will power down the SLIC when the junction temperature exceeds 170°C. A Power Spread sheet is available on the Intersil Web site to assist the designer with this estimate. It can be accessed at www.intersil.com under VolP Applications.

The worst case scenarios for power consumption are short loop applications. Off-hook operation also referred to as the “Talk Mode” (Forward Active), and Ringing (multiple phones) should be considered. When quantifying the power consumption during ringing, one must factor in the ring cadence which is typically (two seconds ringing, four seconds idle). For example, when ringing 5 phones continuously with a maximum peak-to-peak waveform (190V) the power consumed by the SLIC can exceed 1.25W, however with a ringing cadence of two seconds ringing, four seconds idle the power is reduced to 0.6W. When the transient power pulse (2sec) and the period (6sec) are relatively short as is the case for ringing the phone, the average power and the θ_{JA} can be used to accurately predict the Die’s junction temperature. Typically the off hook talk mode is the worst case, and under short loop conditions the SLIC will consume 400 to 500mW.

Thermal Characterization in the MLFP Package

Advancements in thermal modeling have made simulation the preferred method for thermal characterization. With the development and use of Finite Element Analysis (FEA) software, correlation to within 4-8% is routinely achieved between the simulator and laboratory data. Once this very good level of correlation is obtained with the standard JEDEC test boards multiple simulations are performed to generate the data shown in Figures 2 and 3.

Figure 2 summarizes the θ_{ja} of the 32 pin MLFP package for the three JEDEC standard test boards for the RSLIC18. Note that without buried planes or thermal vias the package can’t dissipate heat effectively (78°C/W, 1SOP) which would significantly limit the application. Adding the buried planes and connecting to the upper plane with conductive vias (1S2P-DA) significantly reduces the θ_{ja} to less than 30°C/W (1S2P-DA). Keep in mind that the area of each internal buried plan is 2.92 x 2.92 inches on the test boards and essentially represents an infinite heat sink.

Figure 3 illustrates the effect of various heat sink areas on the θ_{JA} of the HC55185 using the 1S2P-DA test board with thermal vias. This data-set is more applicable for the designer as one can probably assume the MLFP package is being used to realize a dense line circuit solution and the heat sink area will be restricted. The data shows that θ_{JA} ’s of less than 50°C/W can be expected with less than one square inch of heat sink area dedicated to the SLIC.

The question that now comes to mind is how do adjacent SLICs interact thermally and what effect does the heat sink plane have on the overall board temperature in a dense line card application? We can simulate these interactions and predict the maximum die and circuit board temperatures with a relatively simple board level model. Figure 4 illustrates the board layout and defines the conditions for the thermal simulations depicted in Figures 5, 6 and 7. For each simulation the SLICs were spaced one inch apart (center to center) in a 4 by 6 array resulting in a packing density of one square inch per device. All units are dissipating 500mW in the Forward Active loop feed mode (talk mode). Note that the only variable changed in the simulations was the area of the heat sink plane. To keep the simulations manageable the model was set up without any top level interconnects representing a worse case condition for thermal conductivity.

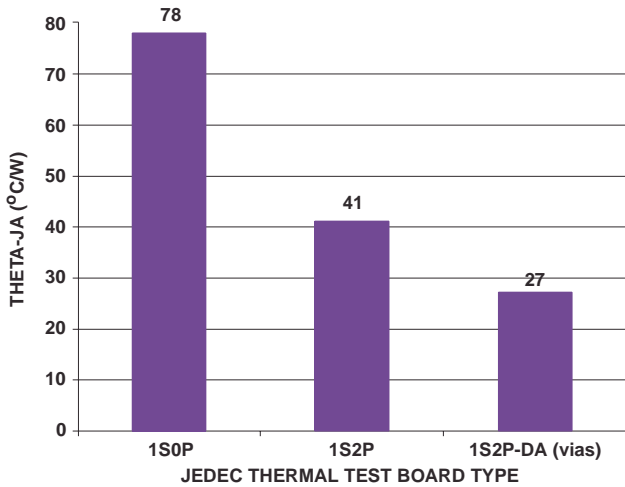


FIGURE 2. MLFP 7x7, 32-LEAD, THETA-JA vs BOARD TYPE

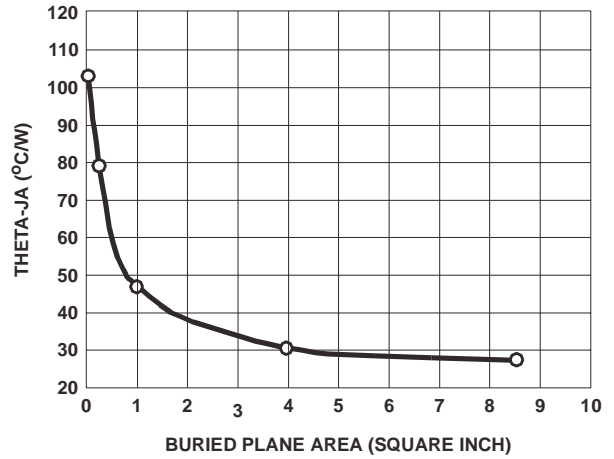


FIGURE 3. MLFP 7x7, 32 LEAD, THETA-JA vs BURIED PLANE AREA (IS2P-DA)

NOTES:

1. Assumes natural convection, board horizontal.
2. "DA" board includes "Direct Attach" thermal vias (16 at 0.3mm drill diameter) per JESD 51-5.
3. In all cases, the package die pad is soldered to the matching board pad.
4. Board metal thickness 100% thick 2 ounce signal, and 95% thick 1 ounce buried copper planes).

MLFP Package Details

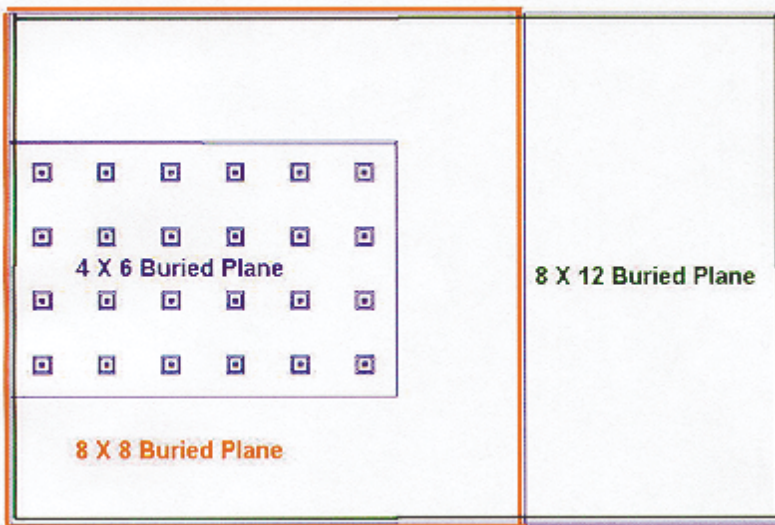
7x7mm-32-pin, 5.3mm pad top, 5.1mm pad bottom.

Board Details:

A 3x4.5" 1S2P-DA ("direct attach") board type with two 1 ounce Cu buried planes and 16 vias connecting to the upper plane only (per JEDEC).

On the board surface, traces fan out radially from the surface. As the plane size is decreased, the 2 ounce surface trace lengths are also decreased so that the traces end slightly inside of the plane size. For the 1/4 x 1/4 inch plane, trace lengths are the same as for the 1/2 x 1/2 inch plane (otherwise there would be no traces, they would be too short).

HC55185 MLF THERMAL MODELING APPLICATION BOARD



- Units spaced 1 inch apart (center to center)
- Heat sink area = 1 sq inch per device
- All devices active and dissipating 500mW
- Board thickness = 1.6mm
- Buried planes = 1oz copper
- Copper thickness = 0.035mm
- FR4 thickness = 0.375mm top/bottom to buried plane
- FR4 thickness = 0.78mm between buried planes
- 16 conductive thermal vias tied to the upper buried plane

FIGURE 4. BOARD SIZE = 8 INCHES x 12 INCHES WITH VARIOUS HEAT SINK PLANES

Simulation #1 (Figure 5) restricts to heat sink plane to the area directly under the 4 x 6 array of SLICs creating an effective heat sink area of 1 square inch/device. With an ambient temperature of 25°C the maximum die temperature reaches 73°C for most units and the board temperature in close proximity to the hottest units reaches approximately 65°C. In this instance the heat sink plane is saturated resulting in an effective θ_{JA} of 96°C/W. Increasing the ambient temperature to 85°C would result in a maximum die temperature of 133°C which is well within the safe operating temperature range of the SLIC (Max = 150°C). Note that the FR4 material is an excellent thermal barrier which could be beneficial for heat sensitive components.

Simulation #2 (Figure 6) increases the heat sink plane to 8 inches x 8 inches providing additional heat sink area to the units on the perimeter of the array. At 25°C ambient, the maximum die temperature of 67°C is observed on the units in the two center rows. The additional heat sink area reduces

the effective θ_{JA} on these devices to 84°C/W. Increasing the ambient temperature to 85°C would result in a maximum die temperature of 127°C.

Simulation #3 (Figure 7) shows the effect of increasing the heat sink plane to match the total board area of 8 inches x 12 inches. In this case the additional heat sink area provides little if any improvement in thermal conductivity for the units in the center rows. This suggests that the packing density of one square inch per unit limits the effective θ_{JA} to approximately 84°C/W for units in the center of the array.

These simulations indicate the heat sink plane can saturate when packing densities are pushed to the extreme, however the resulting θ_{JA} 's are more than adequate to keep the device well under the maximum die temperature of 150°C when operating at 85°C ambient.

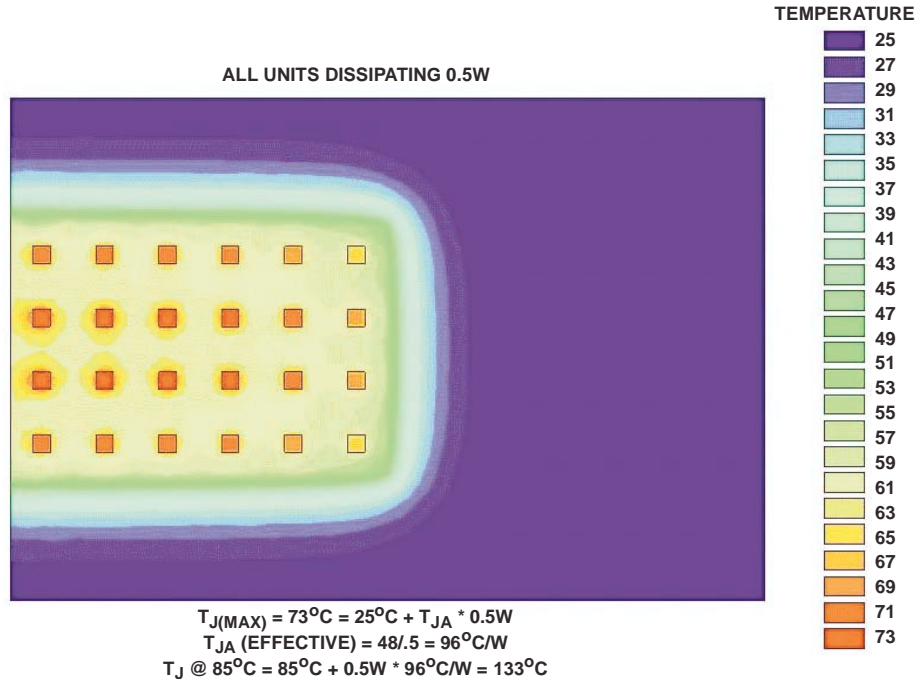


FIGURE 5. HC55185 BOARD LEVEL THERMAL ANALYSIS WITH TOW 4 X 6 INCH BURIED PLANES

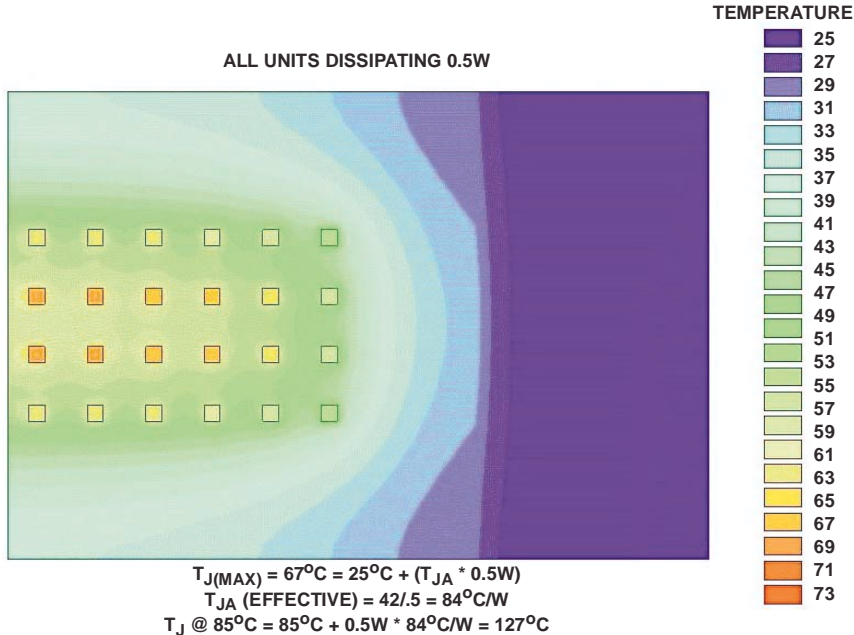


FIGURE 6. HC55185 BOARD LEVEL THERMAL ANALYSIS WITH TWO 8 x 8 INCH BURIED PLANES

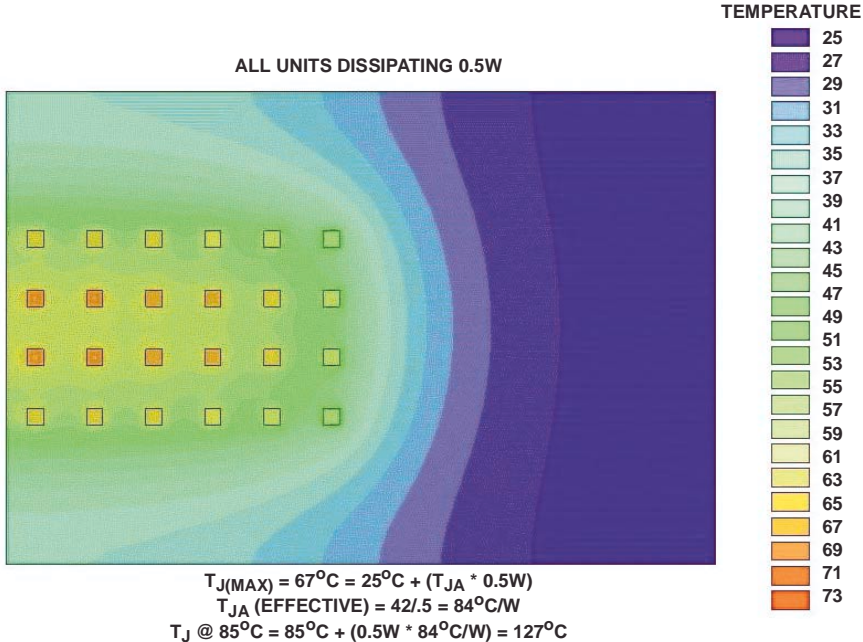


FIGURE 7. HC55185 BOARD LEVEL THERMAL ANALYSIS WITH TWO 8 x 12 INCH BURIED PLANES

Figure 8 further illustrates the impact of device spacing (pitch) on the effective theta-ja. This graph summarizes the results of 8 simulations where the pitch on an infinite matrix of RSLIC18's is varied from .5 inches to 2.92 inches in .25 inch increments. Note the substantial reduction in effective theta-ja that is obtained with only slight increases in device pitch.

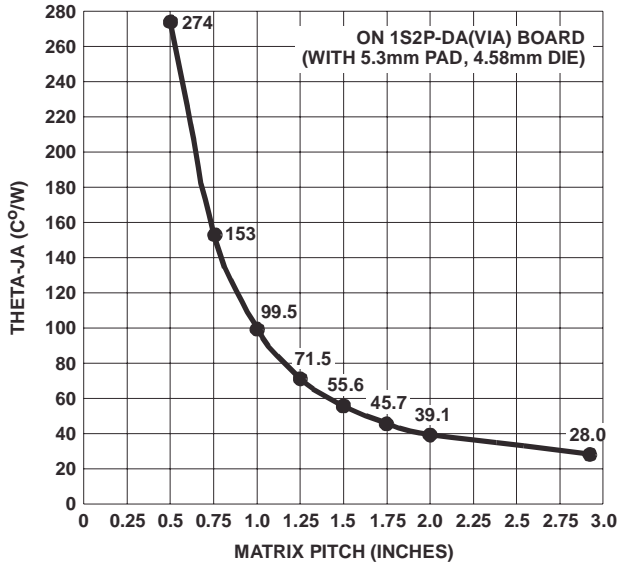


FIGURE 8. THETA-JA vs MATRIX PITCH FOR LARGE SQUARE MATRIX OF 32 PIN 7x7mm MLFPs

Requirements and Recommendations for Circuit Board Layout

- The lead-frame must be electrically tied to V_{BH} . No current flows through the substrate so a current limiting resistor in the order of 100K can be implemented to address any safety issues.
- The electrical connection of the heat sink plane to V_{BH} should be made on the cathode side of the V_{BH} protection diode.
- Dedicate an internal power plane to spread the heat and optimize thermal dissipation.
- Make the heat sink plane as large as possible to minimize board and die temperature. Effective heat sink areas of 1 sq inch/device are acceptable.
- Use conductive copper plated vias to make the electrical and thermal tie to the heat sink plane.

All Intersil products are manufactured, assembled and tested utilizing ISO9000 quality systems. Intersil Corporation's quality certifications can be viewed at www.intersil.com/design/quality

Intersil products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design, software and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

For information regarding Intersil Corporation and its products, see www.intersil.com

Sales Office Headquarters

NORTH AMERICA

Intersil Corporation
7585 Irvine Center Drive
Suite 100
Irvine, CA 92618
TEL: (949) 341-7000
FAX: (949) 341-7123

Intersil Corporation
2401 Palm Bay Rd.
Palm Bay, FL 32905
TEL: (321) 724-7000
FAX: (321) 724-7946

EUROPE

Intersil Europe Sarl
Ave. C - F Ramuz 43
CH-1009 Pully
Switzerland
TEL: +41 21 7293637
FAX: +41 21 7293684

ASIA

Intersil Corporation
Unit 1804 18/F Guangdong Water Building
83 Austin Road
TST, Kowloon Hong Kong
TEL: +852 2723 6339
FAX: +852 2730 1433